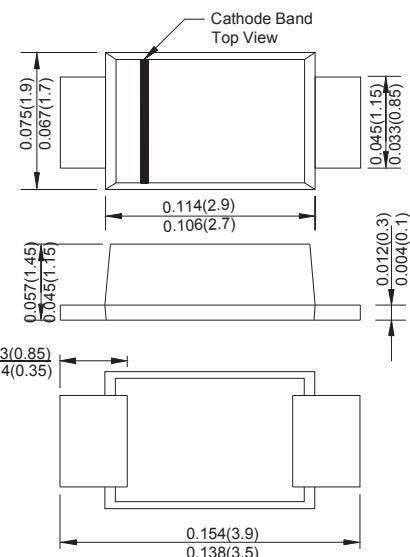


**SILICON RECTIFIERS**
**VOLTAGE RANGE: 50 --- 1000 V CURRENT: 1.0 A**
**FEATURES**

- Low profile space
- Ideal passivated chip junctions
- Low forward voltage drop
- High forward surge capability
- High temperature soldering guaranteed: 260 °C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

**MECHANICAL DATA**

- Case:SOD-123FL molded plastic body over glass passivated chip
- Terminals:Solder plated,solderable per J-STD-002B and JESD22-B102D
- Polarity:Color band denotes cathode end

**SOD123FL**

**MAXIMUM RATINGS AND CHARACTERISTICS**

@ 25°C Ambient Temperature (unless otherwise noted) Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate by 20%.

Characteristic	SYMBOLS	SOD4001 DSR1A	SOD4002 DSR1B	SOD4003 DSR1D	SOD4004 DSR1G	SOD4005 DSR1J	SOD4006 DSR1K	SOD4007 DSR1M	UNITS
Maximum recurrent peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum DC blocking voltage	$V_{DC}$								
Maximum RMS Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average rectified output current	$I_{O(AV)}$								A
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load(JEDECmethod)	$I_{FSM}$								A
Forward Voltage @IF=1.0A	$V_F$								V
Peak Reverse Current at rated DC blocking voltage	@ $T_A=25$ @ $T_A=125$								$\mu A$
Thermal resistance from junction to ambient(Note 1)	$R_{\theta JL}$								pF
Typical Thermal Resistance Junction to Ambient (Note 2)	$R_{\theta JA}$								°C/W
Operating Temperature Range	$T_j$								°C

NOTES:

1. Mounted on FR-4 P.C.B. with 0.9×1.5mm copper pad areas ( $\approx 35\mu m$  thick)

## RATINGS AND CHARACTERISTIC CURVES

Fig.1 Forward Current Derating Curve

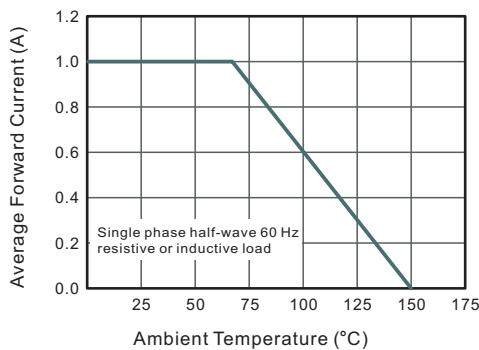


Fig.2 Typical Instantaneous Reverse Characteristics

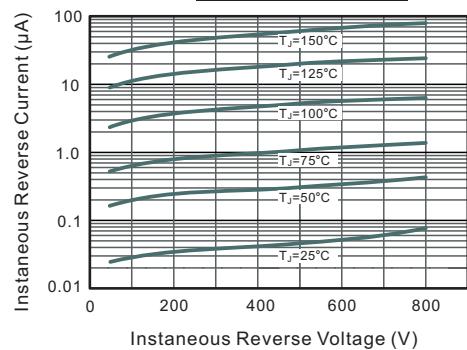


Fig.3 Typical Forward Characteristic

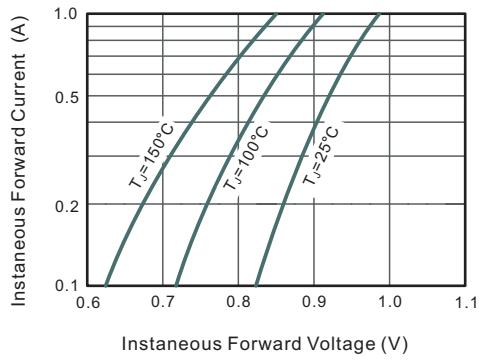


Fig.4 Typical Junction Capacitance

